

1. General description

NPN low V_{CEsat} DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5350PAS-Q

2. Features and benefits

- DFN2020D-3 (SOT1061D) package
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability: I_C and I_{CM}
- Higher efficiency leading to less heat generation
- Reduced printed-circuit board requirements
- Leadless small SMD plastic package with solderable side pads
- Exposed heat sink for excellent thermal and electrical conductivity
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Loadswitch
 - Battery-driven devices
 - Power management
 - · Charging circuits
 - Power switches (e.g. motors, fans)

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
I _C	collector current			-	-	3	А
I _{CM}	peak collector current	limited by T _{j(max)}		-	-	5	А
R _{CEsat}	collector-emitter saturation resistance	I_C = 2 A; I_B = 200 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	100	130	mΩ

nexperia

5. Pinning information

Table 2	Table 2. Pinning information						
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	В	base	3				
2	E	emitter		с			
3	C	collector	I 2 Transparent top view DFN2020D-3 (SOT1061D)	B E sym021			

6. Ordering information

ľ	Table	3.	Ordering	information	1

Type number	Package				
	Name	Description	Version		
PBSS4350PAS-Q	DFN2020D-3	plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); no leads; 3 terminals; 1.3 mm pitch; 2 mm x 2 mm x 0.65 mm body	<u>SOT1061D</u>		

7. Marking

Table 4. Marking codes	
Type number	Marking code
PBSS4350PAS-Q	G6

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	3	А
I _{CM}	peak collector current	limited by T _{j(max)}		-	5	А
I _B	base current			-	0.5	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.5	W
			[2] [3]	-	1	W
			[4]	-	1.2	W
			[5] [6]	-	2	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

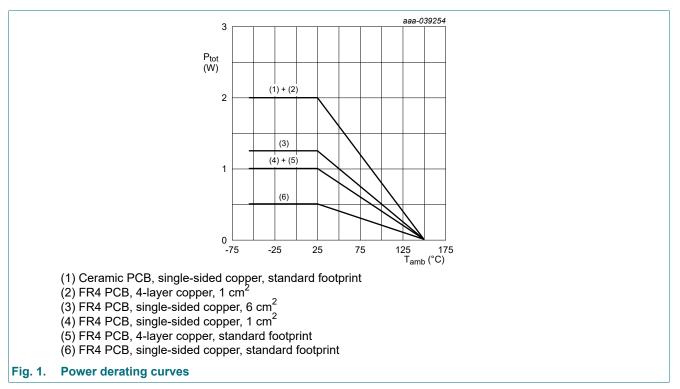
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[5] Device mounted on a ceramic PCB, AI_2O_3 , standard footprint.

[6] Device mounted on a FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 7 cm².



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
R _{th(j-a)} thermal resistance from junction to ambient	in free air [[1]	-	-	250	K/W		
	junction to ambient		[2] [3]	-	-	125	K/W	
			[4]	-	-	100	K/W	
			[5] [6]	-	-	60	K/W	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

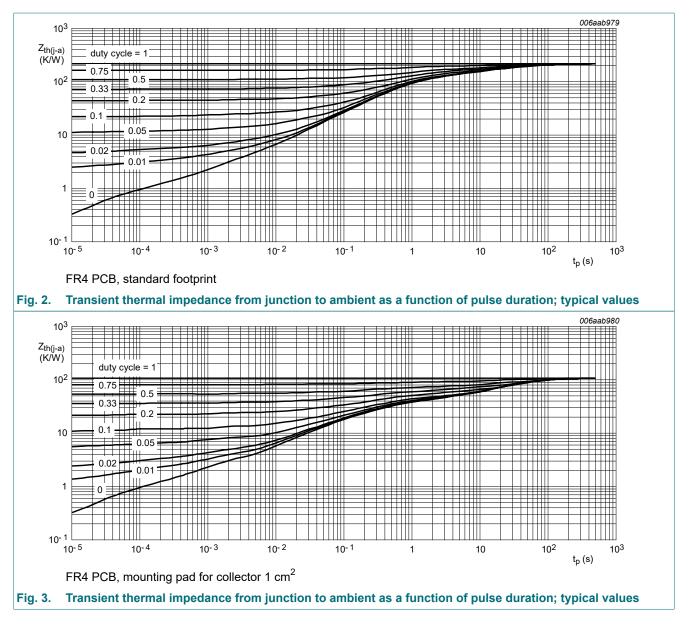
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

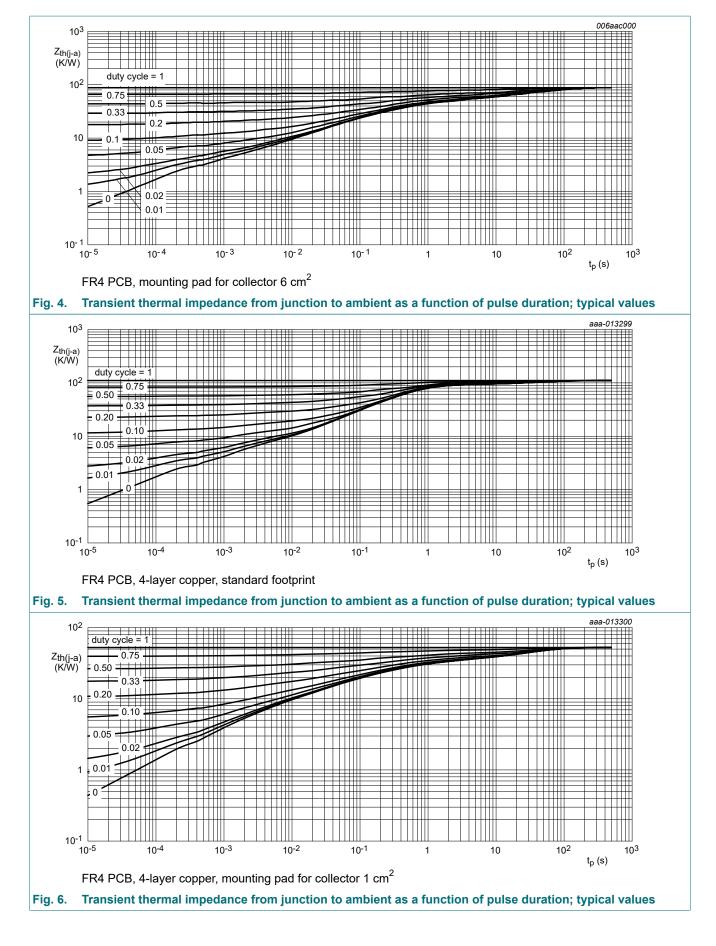
[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

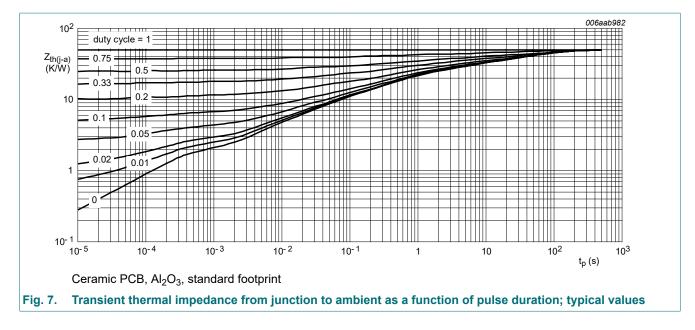
[6] Device mounted on a FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm².



50 V, 3 A NPN low VCEsat transistor



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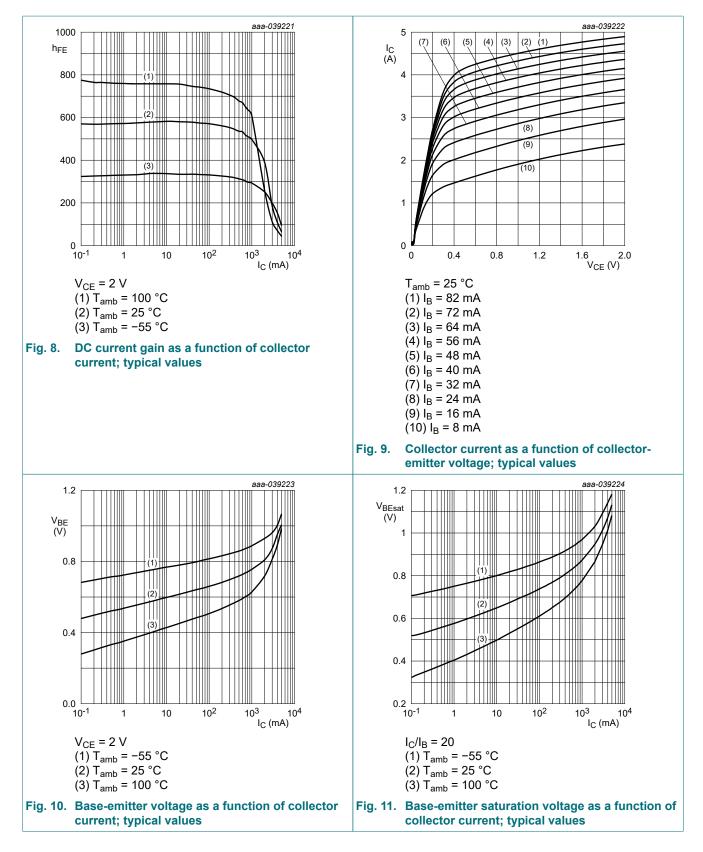


PBSS4350PAS-Q

10. Characteristics

Symbol	Parameter	Conditions	Mir	n Typ	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C	50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _B = 0 A; T _{amb} = 25 °C	50	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C	5	-	-	V
000	collector-base cut-off	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CB} = 50 V; I _E = 0 A; T _j = 150 °C	-	-	50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = 50 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 2 V; I _C = 0.1 A; single pulse; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	300) -	-	
		V _{CE} = 2 V; I _C = 0.5 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	300) -	-	
		V_{CE} = 2 V; I _C = 1 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	300) -	700	
		V_{CE} = 2 V; I _C = 2 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	200) -	-	
		V_{CE} = 2 V; I _C = 3 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	100) -	-	
V _{CEsat}	collector-emitter	I_{C} = 0.5 A; I_{B} = 50 mA; T_{amb} = 25 °C	-	-	80	mV
	saturation voltage	I _C = 1 A; I _B = 50 mA; T _{amb} = 25 °C	-	-	160	mV
		I _C = 2 A; I _B = 100 mA; T _{amb} = 25 °C	-	-	280	mV
		I _C = 2 A; I _B = 200 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	260	mV
		I _C = 3 A; I _B = 300 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	370	mV
R _{CEsat}	collector-emitter saturation resistance	I _C = 2 A; I _B = 200 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	100	130	mΩ
V _{BEsat}	base-emitter saturation	I _C = 2 A; I _B = 100 mA; T _{amb} = 25 °C	-	-	1.1	V
	voltage	I _C = 3 A; I _B = 300 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	1.2	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = 2 V; I _C = 1 A; T _{amb} = 25 °C	-	-	1.1	V
fT	transition frequency	V _{CE} = 5 V; I _C = 100 mA; f = 100 MHz; T _{amb} = 25 °C	100) -	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	25	pF

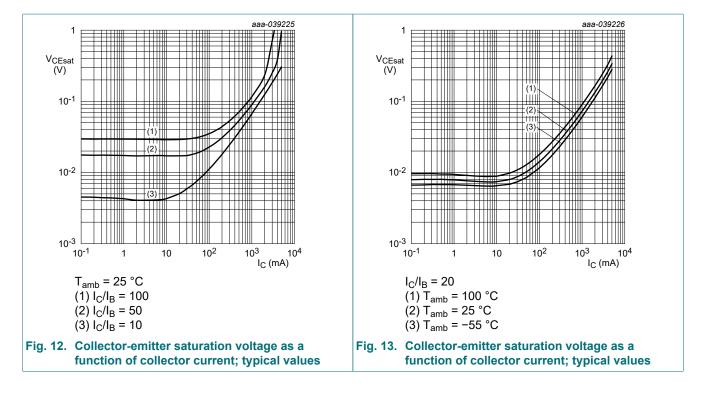
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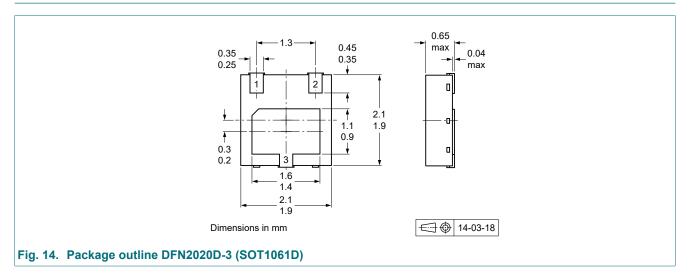


11. Test information

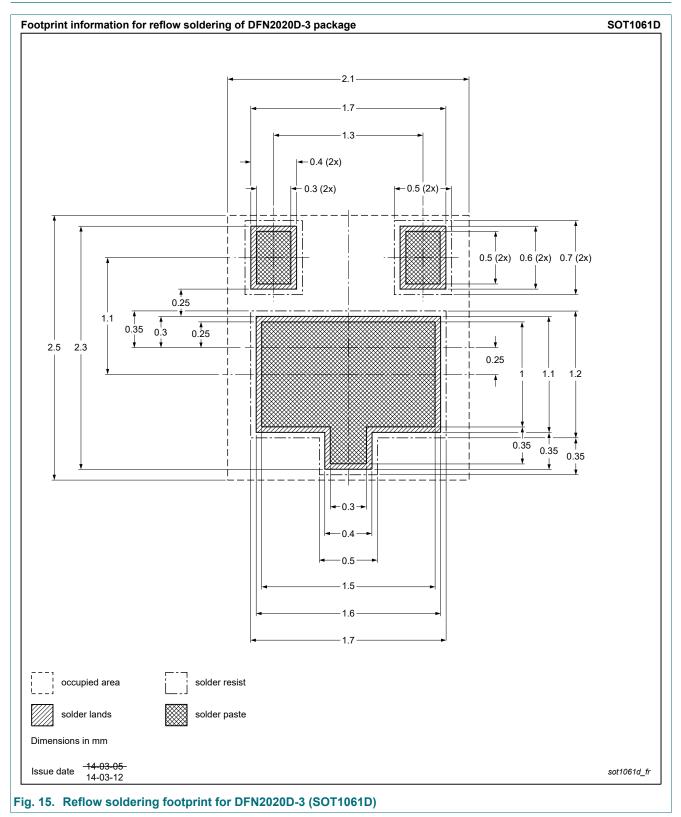
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS4350PAS-Q v.2	20240807	Product data sheet	-	PBSS4350PAS-Q v.1		
Modifications:	Typo Correction from PNP to NPN.					
PBSS4350PAS-Q v.1	20240516	Product data sheet	-	-		

PBSS4350PAS-Q

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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